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## High Voltage LED Series Chip on Board

# LCo<sub>2</sub>6D-Gen.<sub>2</sub>



# High efficacy COB LED package well-suited for use in spotlight applications









#### **Features & Benefits**

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

#### **Applications**

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination



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#### 1. Characteristics

#### a) Absolute Maximum Rating

ltem	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	Ta	-40 ~ +105	ōC	-
Storage Temperature	$T_{stg}$	-40 ~ +120	ōС	-
LED Junction Temperature	ΤJ	150	ōС	-
Case Temperature	Тс	115	ōС	
Forward Current	lF	1840	mA	-
Power Dissipation	P <sub>D</sub>	69	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	=	±0.5	kV	-

## b) Electro-optical Characteristics (I<sub>F</sub> = 720 mA, $T_J$ = 85 $^{\circ}$ C)

ltem	Unit	Rank	Min.	Тур.	Max.
Forward Voltage (V <sub>F</sub> )	V	YZ	31.8	34.6	37.5
		3	70	-	-
Color Rendering Index (Ra)	-	5	80	-	-
		7	90		
Thermal Resistance (junction to chip case)	<sup>2</sup> C/W		-	0.47	-
Beam Angle	Q		-	115	-
Nominal Power	W			24.9	

#### Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ( $T_J = T_C = T_a = 85$  °C)
- 2) Samsungmaintains measurement tolerance of: forward voltage =  $\pm 5$  %, CRI =  $\pm 1$
- 3) Refer to the derating curve, '3. Typical Characteristics Graph'designed within the range.

## c) Luminous FluxCharacteristics (I<sub>F</sub> = 720 mA)

CRI (R <sub>a</sub> )	Nominal	Flux	Flux@ Τ <sub>c</sub> = 85 °C (lm)			
Min.	CCT (K)	Rank	Min.	Тур.	Max.	
	3000	D2	3860	4063	-	
70	4000	D2	3983	4193	-	
	5000	D2	4045	4258	-	
	2700	D2	3401	3580	-	
	3000	D2	3574	3762	-	
	3500	D2	3679	3872	-	
80	4000	D2	3752	3950	-	
	5000	D2	3784	3983	-	
	5700	D2	3784	3983	-	
	6500	D2	3752	3950	-	
	2700	D2	2910	3064	-	
	3000	D2	3061	3223	-	
90	3500	D2	3153	3319	-	
	4000	D2	3218	3387	-	
	5000	D2	3245	3416	-	

#### Notes:

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature ( $T_J = T_C = 85$  °C).
- 2) Samsungmaintains measurement tolerance of: Luminous flux =  $\pm 7$  %, CRI =  $\pm 1$

## 2. Product Code Information

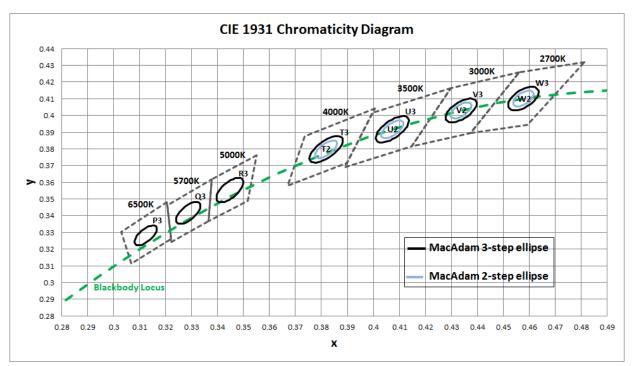
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	н	w	н	Α	н	D	N	G	2	5	Υ	Z	W	3	D	2

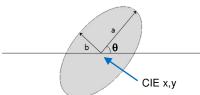
Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	Α	
7 8	Form Factor	HD	СОВ
9	Lens Type	N	No lens
10	Wattage or Model	G	LC026D
11	Internal Code	2	
	CRI & Sorting Temperature	3	Min. 70 (85°C)
12		5	Min. 80 (85°C)
		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8~37.5
		w	2700K
		V	3000K
		U	3500K
15	CCT (K)	Т	4000K
		R	5000K
		Q	5700K
		Р	6500K
16	MacAdam Step	2	MacAdam 2-step
10	імаслиані Этер	3	MacAdam 3-step
17 18	Luminous Flux (Lm)	D2	COB D-series Gen.2 level

## a) Binning Structure (I<sub>F</sub> = 720 mA, $T_J$ = 85 $^{\circ}$ C)

CRI(R <sub>a</sub> ) Min.	Nominal CCT(K)	Product Code	V <sub>F</sub> Rank	Color Rank	Flux Rank	Flux Range (Φ <sub>v</sub> , lm)	
	3000	SPHWHAHDNG23YZV3D2	YZ	V3	D2	3860 ~	
70	4000	SPHWHAHDNG23YZT3D2	YZ	Т3	D2	3983 ~	
	5000	SPHWHAHDNG23YZR3D2	YZ	R3	D2	4045 ~	
	2700	SPHWHAHDNG25YZW2D2	· YZ	W2	D2	3401 ~	
	2700	SPHWHAHDNG25YZW3D2	12	W3	DZ.	3401	
	3000	SPHWHAHDNG25YZV2D2	YZ	V2	D2	3574 ~	
	3000	SPHWHAHDNG25YZV3D2	12	V3	<i>D2</i>	3374	
	3500	SPHWHAHDNG25YZU2D2	YZ	U2	D2	3679 ~	
80	3300	SPHWHAHDNG25YZU3D2	12	U3	<i>D2</i>	3073	
	4000	SPHWHAHDNG25YZT2D2	YZ	T2	D2	3752 ~	
	4000	SPHWHAHDNG25YZT3D2	12	Т3	<i>DE</i>	O/ OL	
	5000	SPHWHAHDNG25YZR3D2	YZ	R3	D2	3784 ~	
	5700	SPHWHAHDNG25YZQ3D2	YZ	Q3	D2	3784 ~	
	6500	SPHWHAHDNG25YZP3D2	YZ	P3	D2	3752 ~	
	2700	SPHWHAHDNG27YZW2D2	YZ	W2	D2	2910 ~	
	2700	SPHWHAHDNG27YZW3D2		W3		2010	
	3000	SPHWHAHDNG27YZV2D2	YZ	V2	D2	3061 ~	
		SPHWHAHDNG27YZV3D2		V3			
90	3500	SPHWHAHDNG27YZU2D2	· YZ	U2	D2	3153 ~	
	3300 "	SPHWHAHDNG27YZU3D2	1 4	U3	DZ.	0100	
	4000	SPHWHAHDNG27YZT2D2	YZ	T2	D2	3218 ~	
	+000	SPHWHAHDNG27YZT3D2	1 4	T3	<i>D2</i>	3∠10 ~	
	5000	SPHWHAHDNG27YZR3D2	YZ	R3	D2	3245 ~	

## b) Chromaticity Region & Coordinates ( $I_F = 720 \text{ mA}, T_J = 85 \,^{\circ}\text{C}$ )





MacAdam Ellipse (W2, W3)									
Step	CIE x	CIE y			b				
2-step	0.4578	0.4101	53.70	0.0054	0.0028				
3-step	0.4578	0.4101	53.70	0.0081	0.0042				

MacAdam Ellipse (V2, V3)									
Step	CIE x	CIE y			b				
2-step	0.4338	0.403	53.22	0.0056	0.0027				
3-step	0.4338	0.4030	53.22	0.0083	0.0041				

MacAdam Ellipse (U2, U3)								
Step	CIE x	CIE y			b			
2-step	0.4073	0.3917	54.00	0.0062	0.0028			
3-step	0.4073	0.3917	54.00	0.0093	0.0041			

MacAdam Ellipse (T2, T3)								
Step	CIE x	CIE y			b			
2-step	0.3818	0.3797	53.72	0.0063	0.0027			
3-step	0.3818	0.3797	53.72	0.0094	0.0040			

MacAdam Ellipse (R3)									
	Step	CIE x	CIE y	θ		b			
	3-step	0.3447	0.3553	59.62	0.0082	0.0035			

MacAdam Ellipse (Q3)						
Step	CIE x	CIE y			b	
3-step	0.3287	0.3417	59.0950	0.0075	0.0032	

MacAdam Ellipse (P3)						
Step	CIE x	CIE y			b	
3-step	0.3123	0.3282	58.5700	0.0067	0.0029	

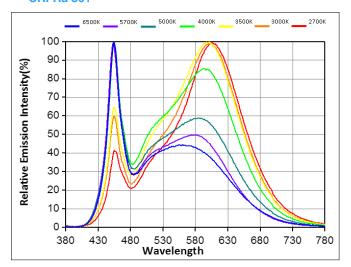
#### Note:

Samsung maintains measurement tolerance of: Cx,  $Cy = \pm 0.005$ 

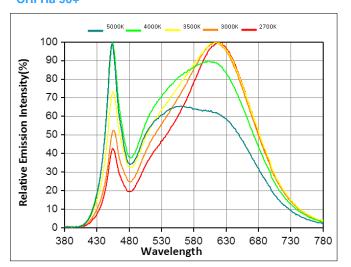
## 3. Typical Characteristics Graphs

## a) Spectrum Distribution (I<sub>F</sub> = 720mA, $T_J$ = 85 $^{\circ}$ C)

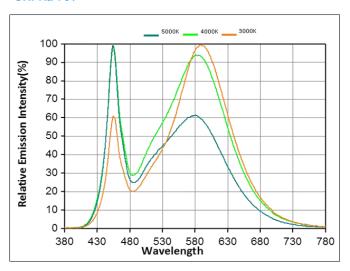
#### CRI Ra 80+



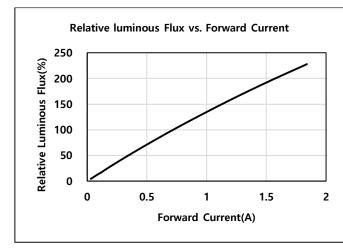
#### CRI Ra 90+

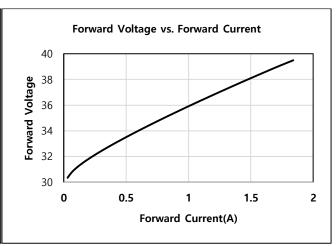


#### CRI Ra 70+

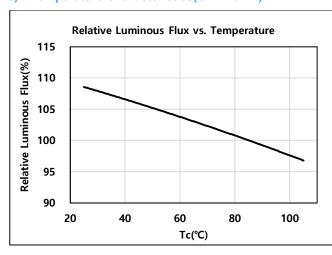


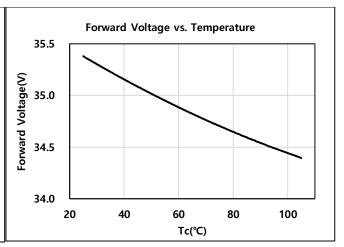
#### b) Forward Current Characteristics (T<sub>J</sub> = 85 °C)



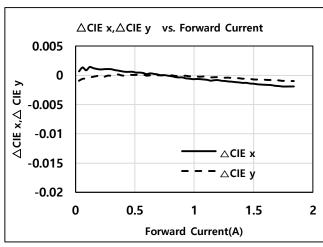


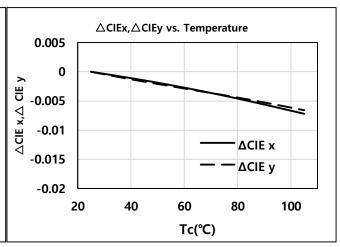
#### c) Temperature Characteristics(I<sub>F</sub> = 720mA)



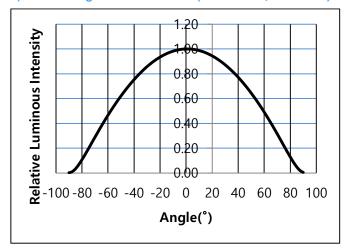


#### d) Color Shift Characteristics (T<sub>J</sub> = 85 °C,I<sub>F</sub> =720mA, CRI = 80+)

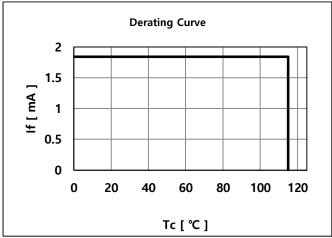




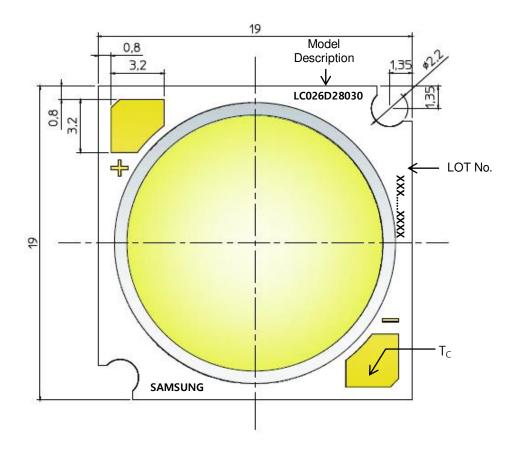
#### e) Beam Angle Characteristics (I<sub>F</sub> = 720 mA, T<sub>J</sub> = 85 °C)

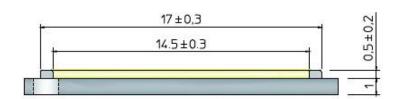


#### f) Derating Characteristics



## 4. Outline Drawing & Dimension





Unit: mm
 Tolerance: ± 0.3 mm

ltem	Dimension	Tolerance	Unit
Length	19.0	±0.30	mm
Width	19.0	±0.30	mm
Height	1.50	±0.20	mm
Light Emitting Surface (LES) Diameter	14.5	±0.30	mm

Note: Denoted product information above is only an example ( LC026D28030 : LC026D, Gen2, CRI80+, 3000K )

## 5. Reliability Test Items & Conditions

## a) Test Items

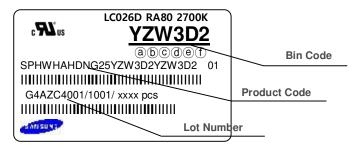
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 <sup>o</sup> C, 90 % RH,, DC Derating, I <sub>F</sub>	1000 h
High Temperature Life Test	85 °C, DC Derating, I <sub>F</sub>	1000 h
Low Temperature Life Test	-40 <sup>o</sup> C, DC,DeratingI <sub>F</sub>	1000 h
High Temperature Storage	120 ºC	1000 h
Low Temperature Storage	-40 °C	1000 h
Temperature Humidity Storage	60 °C, 90% RH	1000h
TemperatureCycle On/Off Test	-40 $^{\circ}$ C/ 85 $^{\circ}$ C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, I <sub>F</sub> = max	100 cycles
ESD (HBM)	R₁: 10 MΩ R₂: 1.5 kΩ C: 100 pF	5 times
ESD (MM)	R₁: 10 MΩ R₂: 0 kΩ C: 200 pF	5 times
Vibration Test	20~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency ↔max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H2S 15 ppm	504h

## b) Criteria for Judging the Damage

ltem	Symbol	Test Condition		nit
	Зуньон	(T <sub>c</sub> = 25 °C)	Min.	Max.
Forward Voltage	$V_{F}$	$I_F = 720 \text{ mA}$	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Ф	I <sub>F</sub> = 720 mA	L.S.L* 0.7	U.S.L * 1.3

#### 6. Label Structure

#### a) Label Structure



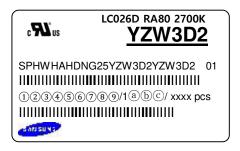
Note: Denoted bincode and product code above is only an example (see description on page 5)

#### Bin Code:

(a) (b): Forward Voltagebin (refer to page 11)(c) (d): Chromaticitybin (refer to page 9-10)(e) (f): Luminous Fluxbin (refer to page 6)

#### b) Lot Number

The lot number is composed of the following characters:



① 3456789 / 1abc / xxxx pcs

1 : Production site (S: Giheung, Korea, G: Tianjin, China)

2 : 4(LED)

3 : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

(4) : Year (Z: 2015, A: 2016, B: 2017...)

(5) : Month (1~9, A, B, C)

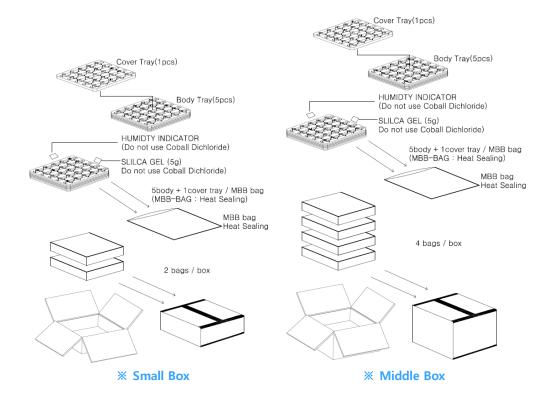
6789 : Day (1~9, A, B~V)

(a) b) c : Product serial number (001 ~ 999)

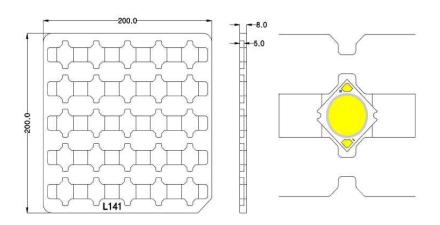
## 7. Packing Structure

	Max. quantity	Dimension(mm)			
Packing material	in pcs of COB	Length	Width	Height	Tolerance
Tray	25	200	200	8	1
Anti-Static Bag	125 (5 trays)	320	270	-	+/- 0.5
Outer Box (Small)	250 (2 bags)	225	225	65	5
Outer Box (Middle)	500 (4 bags)	225	225	130	5

#### a) Packing Structure

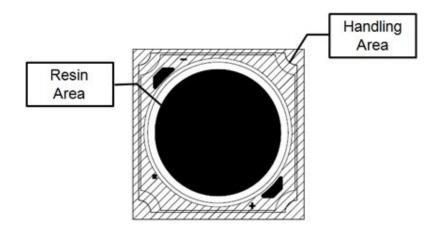


#### b) Tray



#### 8. Precautions in Handling & Use

- This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA
  is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the
  device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at  $23 \pm 5$   $^{\circ}$ C.
- 6) Devices must be baked for 1 hour at  $60 \pm 5$  °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or antielectrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.
  - For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of driving LEDsaround the minimum current level (If\_min), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



# Legal and additional information.

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